CERTIFICATE OF TRANSMISSION BY FACSIMILE (37 CFR 1.8)			Docket No. F1S920030051US1
Applicant(s): Steegan et al.	F15920030051 US1		
Application No.	Filing Date	Examiner	Group Art Unit
10/604,102	6/26/2003	Eckert II, George C.	2815
Invention: SELECTIVE SILICON-ON-INSULATOR ISOLATION STRUCTURES AND METHOD			
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Appl. No.: 10/604,102

Applicant(s): Steegan et al.

Filed.: June 26, 2003

Art Unit: 2815

Dkt. No.: FIS920030051

Examiner: Eckert II, George C.

Title: SELECTIVE SILICON-ON-INSULATOR ISOLATION STRUCTURES AND

METHOD

Honorable Commissioner for Patents P. O. Box 1450 Alexandria, VA 22313-1450 RECEIVED CENTRAL FAX CENTER DEC 2 2 2004

REQUEST FOR RECONSIDERATION

This Request for Reconsideration is being filed in response to the Office Action mailed on October 5, 2004.